

GaAs MMIC DPDT DIVERSITY OR SP3T SWITCH, 4.9 - 5.9 GHz

Typical Applications

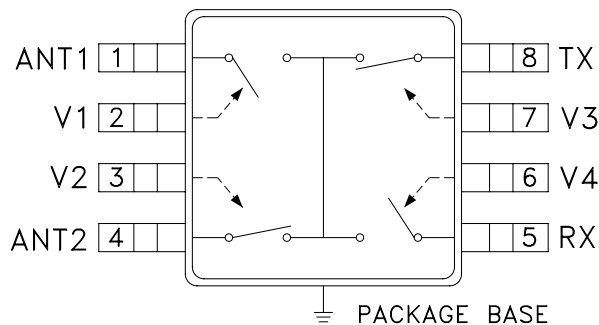
This switch is ideal for use as a DPDT Diversity or SP3T Switch for:

- HiperLAN & 802.11a WLAN
- WiMAX & Fixed Wireless
- UNII Radios
- Multibeam Antenna Switching

Features

- DPDT or SP3T Functionality
- Low Insertion Loss: 1.0 dB
- High IP3: +52 dBm
- High Input P0.1dB: +32 dBm
- Positive Control: 0/+3V or 0/+5V
- Optional "All-Off" State

Functional Diagram



General Description

The HMC436MS8G & HMC436MS8GE are low cost C-band DPDT switches that operate between 4.9 and 5.9 GHz. This switch can operate as an integrated antenna diversity and transmit/receive switch for the 802.11a/HiperLAN and UNII radio platforms. The switch can also operate as a SP3T switch with any of the RF ports serving as the common port. The design provides 20 dB of isolation between antennas and between Tx and Rx ports. The switch features 1 dB insertion loss and high power handling capability. Switch state is controlled using four control voltage lines toggled between 0 and +3 to +5V.

Electrical Specifications,

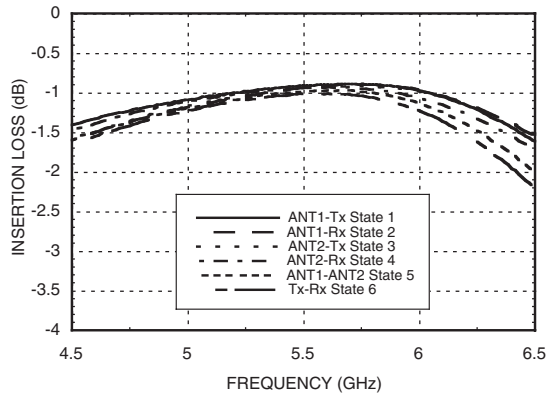
$T_A = +25^\circ \text{C}$, $V_{ctl} = 0/+3 \text{ Vdc}$ (Unless Otherwise Stated), 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	4.9 - 5.1 GHz		1.2	1.5	dB
	5.1 - 5.9 GHz		1.0	1.4	dB
Isolation	4.9 - 5.1 GHz	14	18		dB
	5.1 - 5.4 GHz	16	20		dB
	5.4 - 5.9 GHz	20	25		dB
Return Loss (On State, Any Port)	4.9 - 5.1 GHz	17	20		dB
	5.1 - 5.4 GHz	16	20		dB
	5.4 - 5.9 GHz	13	17		dB
Input Power for 1 dB Compression	4.9 - 5.9 GHz	$V_{ctl} = 0/+3\text{V}$	27	30	dBm
		$V_{ctl} = 0/+5\text{V}$	30	33	dBm
Input Power for 0.1 dB Compression	4.9 - 5.9 GHz	$V_{ctl} = 0/+3\text{V}$	23	26	dBm
		$V_{ctl} = 0/+5\text{V}$	29	32	dBm
Input Third Order Intercept (Two-Tone Input Power= +17 dBm Each Tone)	4.9 - 5.9 GHz	$V_{ctl} = 0/+3\text{V}$	47	50	dBm
		$V_{ctl} = 0/+5\text{V}$	49	52	dBm
Switching Characteristics	4.9 - 5.9 GHz	tRISE / tFALL (10/90% RF)		10	ns
		tON / tOFF (50% CTL to 10/90% RF)		25	ns

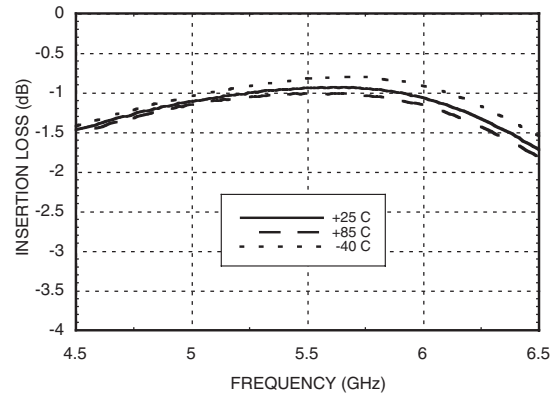


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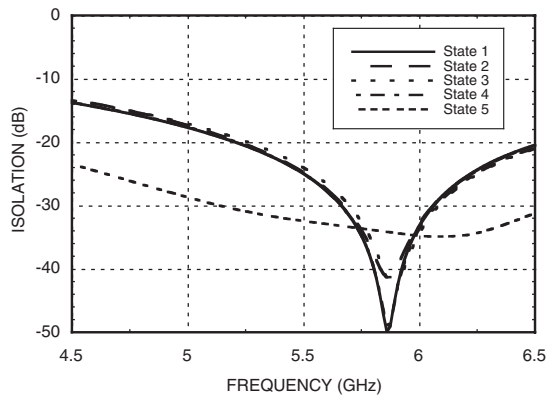
Insertion Loss



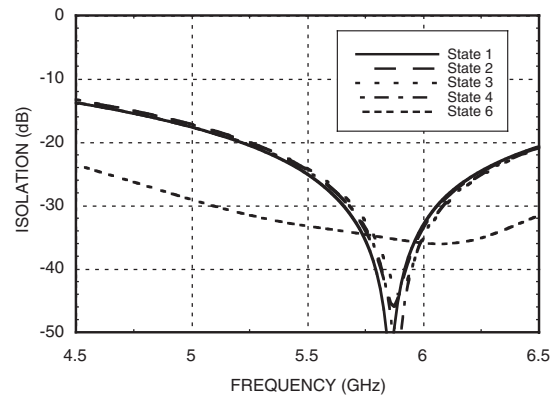
Insertion Loss vs. Temperature



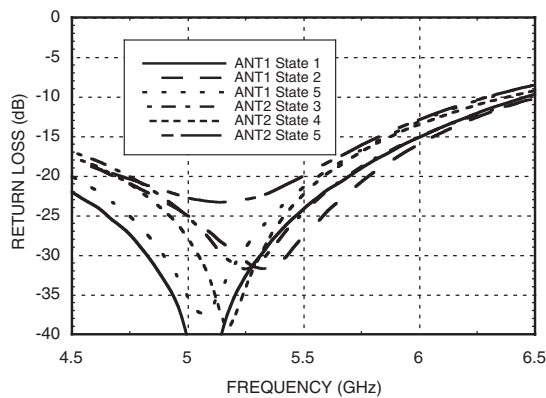
Isolation, Tx & Rx



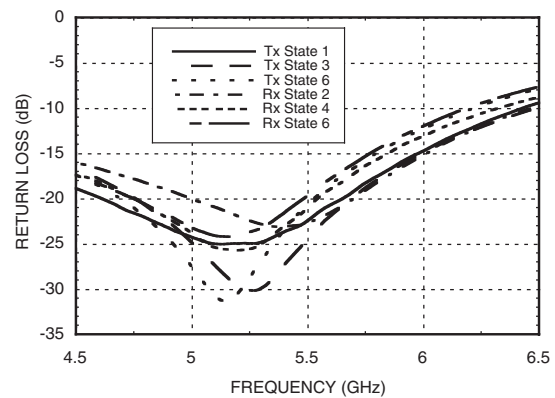
Isolation, ANT1 & ANT2



Return Loss, ANT1 & ANT2



Return Loss, Tx & Rx

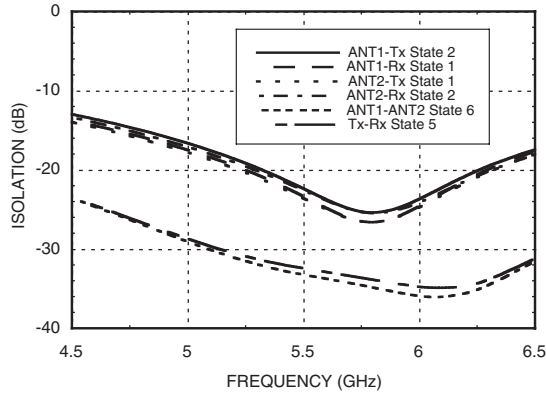




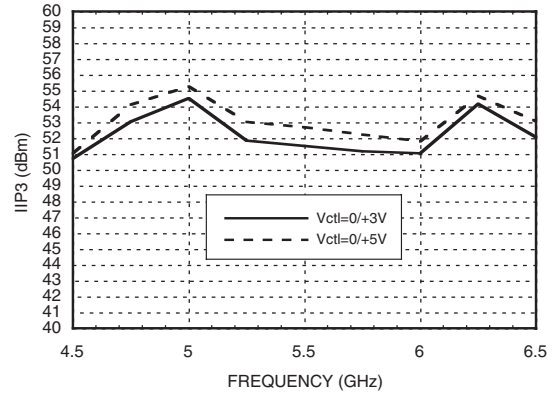
HMC436MS8G / 436MS8GE

GaAs MMIC DPDT DIVERSITY OR SP3T SWITCH, 4.9 - 5.9 GHz

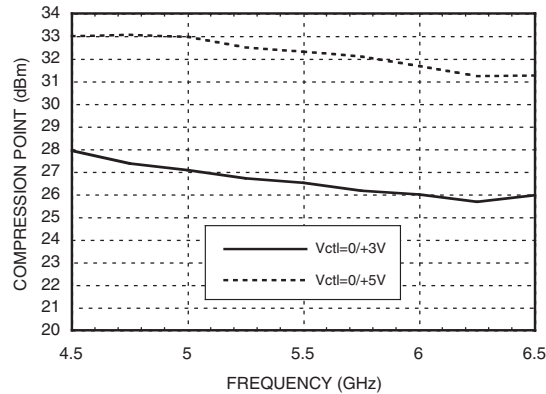
Isolation, ANT1 / ANT2 - Tx / Rx



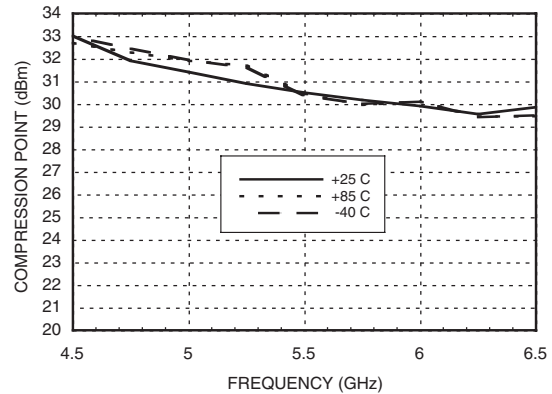
Input IP3 *



Input 0.1 dB Compression Point



Input 1 dB Compression Point, Vctl= 0/+3V



Control Voltages

State	Bias Condition
Low	0 to +0.5 Vdc @ 20 μ A
High	+3.0 to +5.5 Vdc @ 20 μ A Typ.

Truth Table

Path	V1	V2	V3	V4	State
ANT1 - Tx	High	Low	High	Low	1
ANT1 - Rx	High	Low	Low	High	2
ANT2 - Tx	Low	High	High	Low	3
ANT2 - Rx	Low	High	Low	High	4
ANT1 - ANT2	High	High	Low	Low	5
Tx - Rx	Low	Low	High	High	6
All Off*	Low	Low	Low	Low	7

* External components are necessary if "all off" isolation state is desired. See HMC436MS8G product note.

* Two-tone input power = +17 dBm each tone, 1 MHz spacing.

Absolute Maximum Ratings

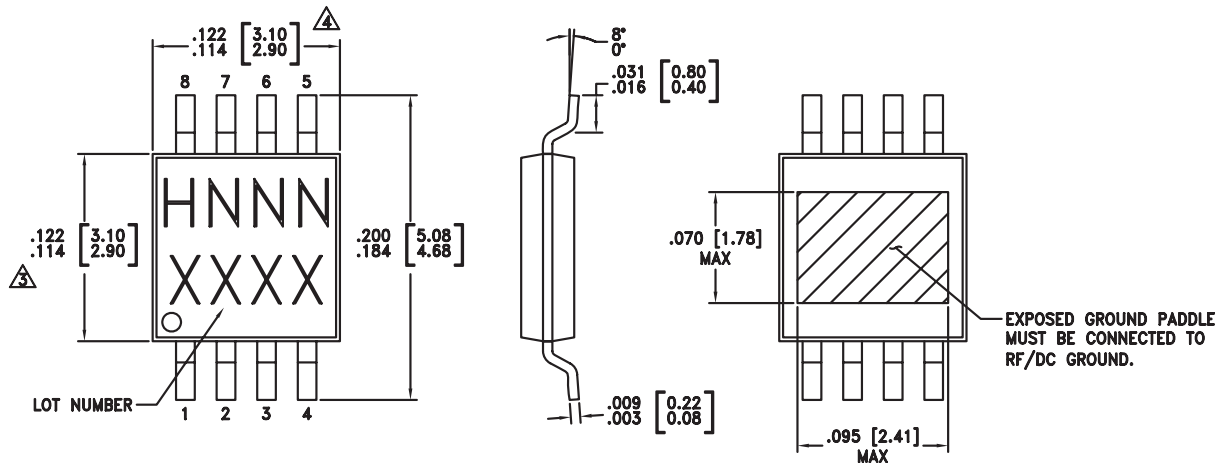
RF Input Power $V_{ctl} = 0/+3V$	+30 dBm
Control Voltage Range (V1, V2, V3, V4)	-0.5 to +7.5 Vdc
Hot Switch Power Level ($V_{ctl} = 0/+3V$)	+26 dBm
Channel Temperature	150 °C
Continuous P_{diss} (T=85 °C) (derate 16.7 mW/ °C above 85°C)	1 W
Thermal Resistance	60 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

DC blocking capacitors are required at ports ANT1, ANT2, Tx, Rx.





**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
-  DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
-  DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC436MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H436 XXXX
HMC436MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H436</u> XXXX

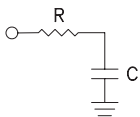

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

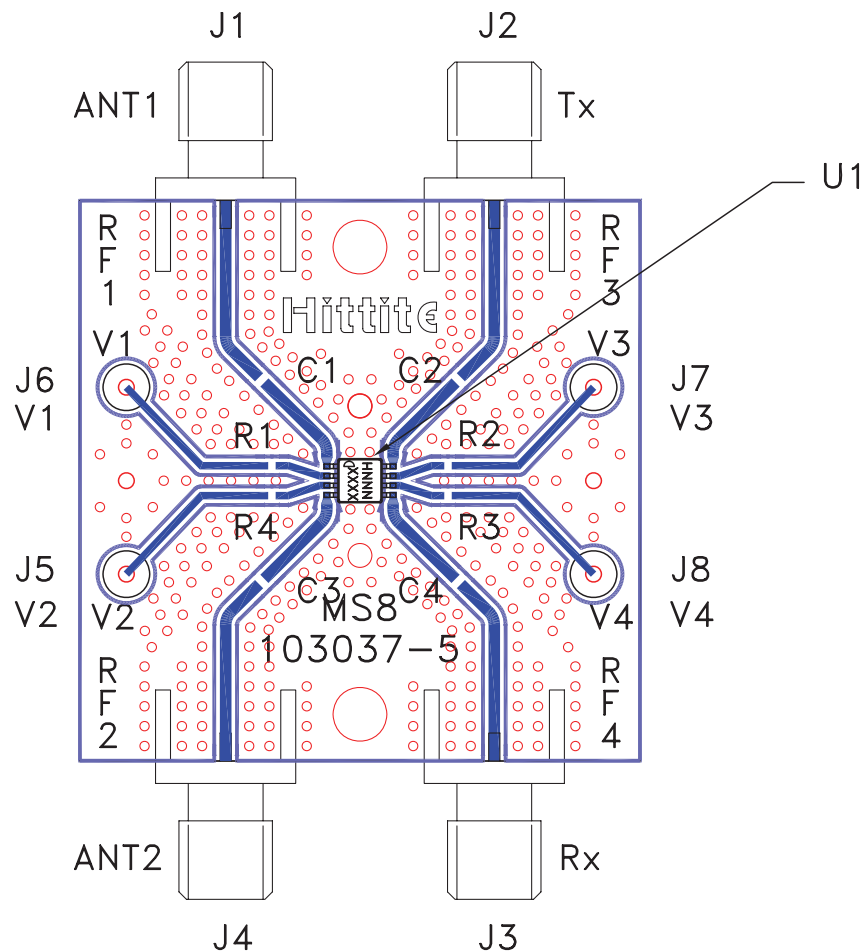
[3] 4-Digit lot number XXXX



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4	ANT1, ANT2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
2, 3, 6, 7	V1, V2, V4, V3	See truth and control voltage tables.	
5, 8	Rx, Tx	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
	GND	Package bottom has exposed metal paddle that must be connected to PCB RF ground.	

Evaluation PCB



List of Materials for Evaluation PCB 103132 [1]

Item	Description
J1 - J4	PCB Mount SMA Connector
J5 - J8	DC Pin
C1 - C4	100 pF Capacitor, 0402 Pkg.
R1 - R4 [3]	100 Ohm Resistor, 0402 Pkg.
U1	HMC436MS8G / HMC436MS8GE DPDT Diversity or SP3T Switch
PCB [2]	103037 Evaluation PCB 1.5" x 1.5"

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

[3] These optional resistors will provide isolation between the DC and RF circuitry.

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown above. A sufficient number of vias should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite upon request.